NSN 5961-01-572-5404

Diode Semiconductor Device - Page 1 of 1



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Function For Which Designed:
Rectifier
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 repetitive peak reverse voltage and 120.0 nonrepetitive peak reverse voltage
Current Rating Per Characteristic:
40.00 amperes collector current, dc of standard range and 20.00 amperes drain current megahertz
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Terminal Type And Quantity:
1 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A110a0